

9. Tutorial on Optical Sources and Detectors

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Problem 1: Amplitude-phase coupling

Modulating the injection current of a semiconductor laser affects both the real part and the imaginary part of the complex refractive index $\underline{n} = n - jn_i$ within the active zone. To a first-order approximation, the change of n and n_i are linked by the so-called Henry-factor α_H ,

$$\alpha_H = \frac{\partial n / \partial n_c}{\partial n_i / \partial n_c}.$$

The imaginary part of the refractive index is connected to the material gain g and the gain rate G by

$$g = -2k_0 n_i; \quad G = v_g g,$$

where v_g denotes the group velocity of the signal. If the refractive index in the active zone changes by a small amount, then the effective index of the guided mode changes by $\Delta n_e = \Gamma \cdot \Delta n$, where Γ denotes the field confinement factor.

- a) How does the change of n influence the emission frequency, when assuming that the laser always emits in the same longitudinal mode? Show that the change $\Delta\omega$ of emission frequency can be expressed by

$$\Delta\omega = -\frac{\omega}{n_{eg}} \Delta n_e,$$

where $n_{eg} = n_e + \omega \frac{\partial n_e}{\partial \omega}$ denotes the effective group refractive index of the mode.

→ From the resonance condition $n_e \omega = \text{const}$, therefore the derivative must be zero

$$\begin{aligned} d(n_e \omega) &= \frac{\partial(n_e \omega)}{\partial \omega} d\omega + \frac{\partial(n_e \omega)}{\partial n_e} dn_e = 0 \\ &= \left(n_e + \omega \frac{\partial n_e}{\partial \omega} \right) d\omega + \omega dn_e \\ &= n_{eg} d\omega + \omega dn_e \\ \Rightarrow \Delta\omega &= -\frac{\omega}{n_{eg}} \Delta n_e \end{aligned}$$

- b) Calculate the instantaneous deviation $\Delta\omega$ from the steady-state emission frequency as a function of the instantaneous laser gain rate $G(t)$. Start from the definition of the Henry-factor. During the derivation use the solution obtained from part a) and the fact that $\Gamma G_0 = 1/\tau_p$ in steady-state. The resulting equation can be brought to the following form:

$$\Delta\omega = \frac{\alpha_H}{2} \left(\Gamma G - \frac{1}{\tau_p} \right)$$

$$\rightarrow \Delta(\Gamma G) = \Gamma G - \Gamma G_0 = \Gamma G - \frac{1}{\tau_p}$$

$$\Delta(\Gamma G) = \Gamma \Delta G = \Gamma \Delta(v_g g) = \Gamma v_g \Delta g$$

From the definition of the Henry-factor one can deduce the following relation:

$$\alpha_H = \frac{\Delta n}{\Delta n_i} = -2k_0 \frac{\Delta n}{\Delta g}.$$

This can be inserted into the equation above:

$$\Gamma v_g \Delta g = -2k_0 \Gamma v_g \frac{\Delta n}{\alpha_H} = -2k_0 v_g \frac{\Delta n_e}{\alpha_H} = \Gamma G - \frac{1}{\tau_p}.$$

After inserting the relation found in part a) it is possible to calculate

$$\Delta\omega = \frac{\alpha_H}{2} \left(\Gamma G - \frac{1}{\tau_p} \right)$$

- c) What are the consequences of this behavior for a time dependent optical signal, which was generated by directly modulating the injection current of a laser?
- A time dependent optical signal is generated by varying the laser injection current. This induces also a time dependent gain factor, which then translates into a time dependent change of the instantaneous emission frequency. Hence an intensity modulation comes along with a frequency modulation. This effect is also called a chirp.

Problem 2: Sensitivity of a photodiode

- a) A photodiode has a sensitivity of $S = 1 \text{ A/W}$ and is illuminated by an optical signal with power of -30 dBm . What is the photocurrent generated by the device?
- $i_p = S \cdot P = 1 \text{ A/W} \cdot 1 \mu\text{W} = 1 \mu\text{A}$
- b) The data sheet of a newly developed Si pin photodiode claims a sensitivity of $S = 0.7 \text{ mA/mW}$ at a wavelength of $\lambda = 0.8 \mu\text{m}$. Comment this statement.
- $\eta = \frac{Shc}{e\lambda} = 1.085$

This would mean that more electrons are generated than there are photons available, which is a contradiction.

Questions and Comments:

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